



K. Memory (Design & Process Technology) 분과

2021년 1월 28일(목), 16:30-18:00 / 채널 D

[TD5-K] Emerging Memory I

좌장: 김상범 교수 (서울대학교), 김시준 교수 (강원대학교)

<p>TD5-K-1 16:30-17:00</p>	<p>[초청] Device Requirements and Applications of Memristor-Based Artificial Neural Network Hardware</p> <p>Shinhyun Choi, Taeryong Kim, Beomjin Kim, and Sion Park <i>The School of Electrical Engineering, KAIST</i></p>
<p>TD5-K-2 17:00-17:15</p>	<p>Superlattice-like GeTe/Sb₂Te₃ Phase Change Material Synthesized by Atomic Layer Deposition and Its Electrical Performance</p> <p>Chanyoung Yoo^{1,2}, Eui-sang Park^{1,2}, Woohyun Kim^{1,2}, Jeong Woo Jeon^{1,2}, Wonho Choi^{1,2}, Byongwoo Park^{1,2}, Gyuseung Han^{1,2,3}, Yoon Kyeong Lee⁴, and Cheol Seong Hwang^{1,2} ¹<i>Department of Materials Science and Engineering, Seoul National University,</i> ²<i>Inter-University Semiconductor Research Center, Seoul National University,</i> ³<i>Center for Electronic Materials, KIST,</i> ⁴<i>Division of Advanced Materials Engineering, Jeonbuk National University</i></p>
<p>TD5-K-3 17:15-17:30</p>	<p>Memristive Reservoir Computing for Medical Diagnosis</p> <p>Yoon Ho Jang^{1,2}, Ji Hun Kim^{1,2}, Jeong Woo Jeon^{1,2}, Woo Hyun Kim^{1,2}, and Cheol Seong Hwang^{1,2} ¹<i>Department of Materials Science and Engineering, Seoul National University,</i> ²<i>Inter-University Semiconductor Research Center, Seoul National University</i></p>
<p>TD5-K-4 17:30-17:45</p>	<p>Synaptic Weight Enhanced IGZO Nanofiber Channel Transistor with Ta₂O₅-Barrier Stacked Chitosan-Electric-Double Layer</p> <p>Sung-Hun Kim and Won-Ju Cho <i>Department of Electronic Materials Engineering, Kwangwoon University</i></p>
<p>TD5-K-5 17:45-18:00</p>	<p>Interface Dipole Modulation Device: The New Candidate of Non-volatile Memory</p> <p>Giuk Kim and Sanghun Jeon <i>School of Electrical Engineering, KAIST</i></p>